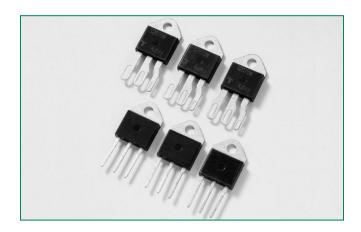


# Sxx35x Series





#### **Description**

Excellent unidirectional switches for phase control applications such as heating and motor speed controls.

Standard phase control SCRs are triggered with few milliamperes of current at less than 1.5V potential.

#### **Features & Benefits**

- RoHS compliant
- Glass passivated junctions
- Voltage capability up to 1000 V
- Surge capability up to 500 A

#### **Agency Approval**

Agency	Agency File Number	
<b>.</b> 21	J & K Packages: E71639	

#### **Applications**

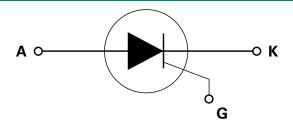
Typical applications are AC solid-state switches, industrial power tools, exercise equipment, white goods and commercial appliances.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.

#### **Main Features**

Symbol	Value	Unit
I <sub>T(RMS)</sub>	35	А
$V_{DRM}/V_{RRM}$	400 to 1000	V
I <sub>GT</sub>	40	mA

### **Schematic Symbol**



### **Absolute Maximum Ratings**

Symbol	Parameter	Test Conditions	Value	Unit
I <sub>T(RMS)</sub>	RMS on-state current	T <sub>c</sub> = 95°C	35	А
I <sub>T(AV)</sub>	Average on-state current	T <sub>c</sub> = 95°C	22.0	А
Dock non repetitive ourse current		single half cycle; $f = 50Hz$ ; $T_{J}$ (initial) = 25°C 425		А
<sup>I</sup> TSM	Peak non-repetitive surge current si	single half cycle; f = 60Hz; T <sub>J</sub> (initial) = 25°C	500	A
l²t	I²t Value for fusing	$t_{p} = 8.3 \text{ ms}$	1035	A <sup>2</sup> s
di/dt	Critical rate of rise of on-state current	f = 60Hz ; T <sub>J</sub> = 125°C	150	A/µs
I <sub>GM</sub>	Peak gate current	T <sub>J</sub> = 125°C	3.5	А
P <sub>G(AV)</sub>	Average gate power dissipation T <sub>J</sub> = 125°C		0.8	W
T <sub>stg</sub>	Storage temperature range	-40 to 150	°C	
T <sub>J</sub>	Operating junction temperature range		-40 to 125	°C



Electrical Characteristics (T, =	25°C, unless otherwise specified)
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Symbol	Test Conditions	Value	Unit		
1			MAX.	40	mA
I <sub>GT</sub>	$V_D = 12V; R_L = 30\Omega$		MIN.	5	IIIA
V <sub>GT</sub>			MAX.	1.5	V
		400V		450	
	\/ \/ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	600V		425	V/µs
	$V_{\rm D} = V_{\rm DRM}$ ; gate open; $T_{\rm J} = 100 {\rm ^{\circ}C}$ dv/dt	800V		400	
dv/dt		1000V	MIN.	200	
		400V		350	
	$V_D = V_{DRM}$ ; gate open; $T_J = 125$ °C	600V		325	
		800V		300	
$V_{GD}$	$V_{D} = V_{DRM}$ ; $R_{L} = 3.3 \text{ k}\Omega$ ; $T_{J} = 125^{\circ}\text{C}$		MIN.	0.2	V
I <sub>H</sub>	$I_T = 400 \text{mA} \text{ (initial)}$		MAX.	50	mA
t <sub>q</sub>	(1)		MAX.	35	μs
t <sub>gt</sub>	$I_{G} = 2 \times I_{GT}$ ; PW = 15 $\mu$ s; $I_{T} = 70$ A		TYP.	2	μs

Notes:

(1)  $I_T=2A$ ;  $t_p=50\mu s$ ;  $dv/dt=5V/\mu s$ ;  $di/dt=-30A/\mu s$ 

#### **Static Characteristics**

Symbol	Test Conditions				Value	Unit
V <sub>TM</sub>		$I_{T} = 70A; t_{p} = 380 \mu s$		MAX.	1.8	V
		T 250C	400 – 600V		10	
		$T_J = 25^{\circ}C$	800 – 1000V		20	
I <sub>DRM</sub> / I <sub>RRM</sub> V <sub>DRM</sub> / V <sub>RRM</sub>		400 – 600V		1000		
	V <sub>DRM</sub> / V <sub>RRM</sub>	T <sub>J</sub> = 100°C	800V	MAX.	1500	μΑ
		1000V		3000		
		T 1050C	400 – 600V		2000	
		$T_J = 125^{\circ}C$	800V		3000	

## **Thermal Resistance**

Symbol	Parameter	Value	Unit
$R_{\theta(J-C)}$	Junction to case (AC)	0.7	°C/W

### **Additional Information**







Resources



Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

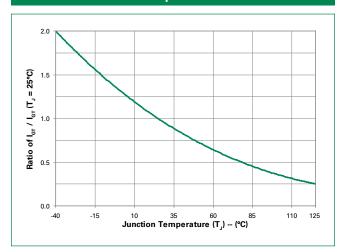


Figure 3: Normalized DC Holding Current vs. Junction Temperature

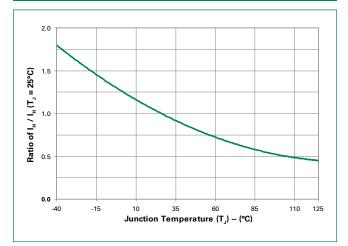


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

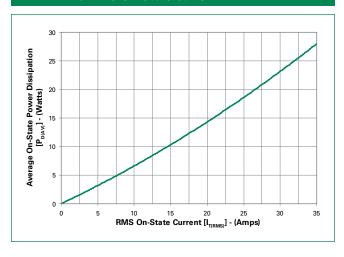


Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature

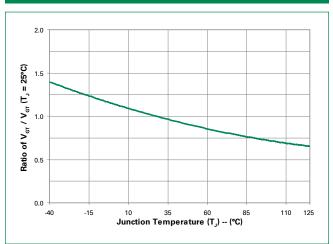


Figure 4: On-State Current vs. On-State Voltage (Typical)

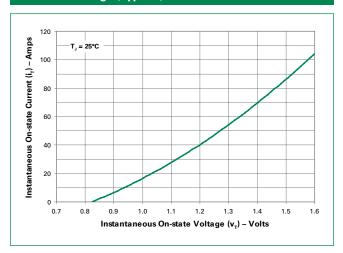


Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current

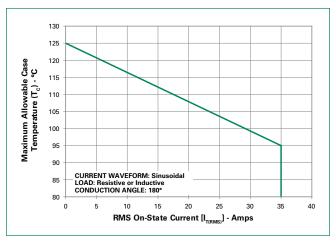
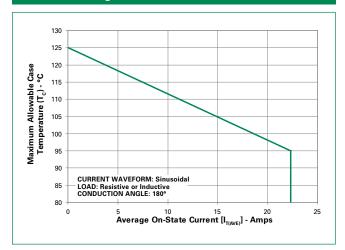




Figure 7: Maximum Allowable Case Temperature vs.
Average On-State Current



**Figure 8: Peak Capacitor Discharge Current** 

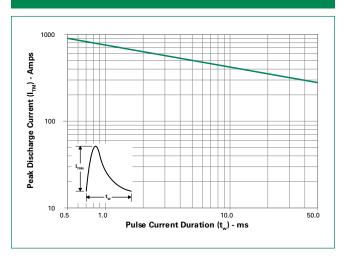


Figure 9: Peak Capacitor Discharge Current Derating

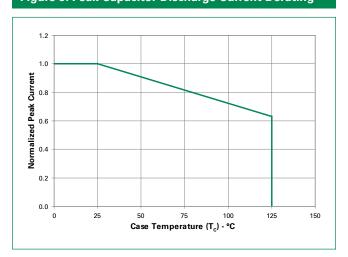
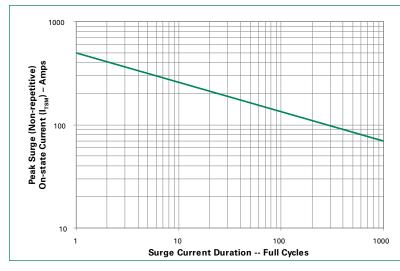


Figure 10: Surge Peak On-State Current vs. Number of Cycles



SUPPLY FREQUENCY: 60 Hz Sinusoidal LOAD: Resistive

RMS On-State Current: [ $I_{T(RMS)}$ ]: Maximum Rated Value at Specified Case Temperature

#### Notes:

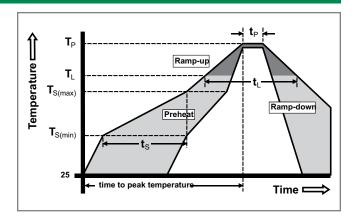
- 1. Gate control may be lost during and immediately following surge current interval.
- Overload may not be repeated until junction temperature has returned to steady-state rated value.

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Specifications are subject to change without notice.
Revised: 12/14/14



#### **Soldering Parameters**

Reflow Condition		Pb – Free assembly	
	-Temperature Min (T <sub>s(min)</sub> )	150°C	
Pre Heat	-Temperature Max (T <sub>s(max)</sub> )	200°C	
	-Time (min to max) (t <sub>s</sub> )	60 – 180 secs	
Average ramp up rate (Liquidus Temp) (T <sub>L</sub> ) to peak		5°C/second max	
T <sub>S(max)</sub> to T <sub>L</sub> - Ramp-up Rate		5°C/second max	
Reflow	-Temperature (T <sub>L</sub> ) (Liquidus)	217°C	
Reliow	-Temperature (t <sub>L</sub> )	60 – 150 seconds	
PeakTemp	erature (T <sub>P</sub> )	260+0/-5 °C	
Time within 5°C of actual peak Temperature (t <sub>p</sub> )		20 – 40 seconds	
Ramp-dov	vn Rate	5°C/second max	
Time 25°C	to peak Temperature (T <sub>P</sub> )	8 minutes Max.	
Do not exc	ceed	280°C	



# **Physical Specifications**

Terminal Finish	100% Matte Tin-plated
Body Material	UL recognized epoxy meeting flammability classification 94V-0
Lead Material	Copper Alloy

#### **Design Considerations**

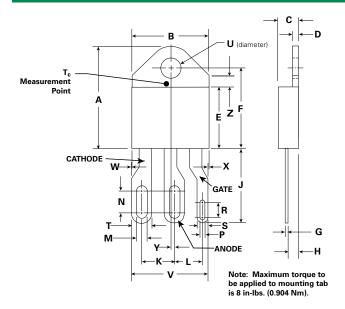
Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

# **Environmental Specifications**

Test	Specifications and Conditions	
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours	
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time	
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity	
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C	
Low-Temp Storage	1008 hours; -40°C	
Thermal Shock	MIL-STD-750, M-1056 10 cycles; 0°C to 100°C; 5-min dwelltime at each temperature; 10 sec (max) transfer time between temperature	
Autoclave	EIA / JEDEC, JESD22-A102 168 hours (121°C at 2 ATMs) and 100% R/H	
Resistance to Solder Heat	MIL-STD-750 Method 2031	
Solderability	ANSI/J-STD-002, category 3, Test A	
Lead Bend	MIL-STD-750, M-2036 Cond E	

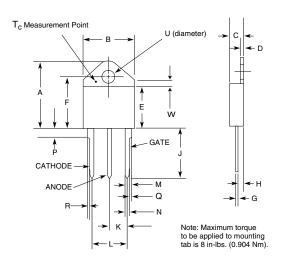


# Dimensions - TO- 218X (J Package) — Isolated Mounting Tab



Dimension	Inc	hes	Millim	eters
Dimension	Min	Max	Min	Max
А	0.810	0.835	20.57	21.21
В	0.610	0.630	15.49	16.00
С	0.178	0.188	4.52	4.78
D	0.055	0.070	1.40	1.78
Е	0.487	0.497	12.37	12.62
F	0.635	0.655	16.13	16.64
G	0.022	0.029	0.56	0.74
Н	0.075	0.095	1.91	2.41
J	0.575	0.625	14.61	15.88
K	0.256	0.264	6.50	6.71
L	0.220	0.228	5.58	5.79
М	0.080	0.088	2.03	2.24
N	0.169	0.177	4.29	4.49
Р	0.034	0.042	0.86	1.07
R	0.113	0.121	2.87	3.07
S	0.086	0.096	2.18	2.44
Т	0.156	0.166	3.96	4.22
U	0.164	0.165	4.10	4.20
V	0.603	0.618	15.31	15.70
W	0.000	0.005	0.00	0.13
Χ	0.003	0.012	0.07	0.30
Υ	0.028	0.032	0.71	0.81
Z	0.085	0.095	2.17	2.42

# Dimensions – TO- 218AC (K Package) — Isolated Mounting Tab



Dimension	Inc	hes	Millim	neters
Difficusion	Min	Max	Min	Max
А	0.810	0.835	20.57	21.21
В	0.610	0.630	15.49	16.00
С	0.178	0.188	4.52	4.78
D	0.055	0.070	1.40	1.78
Е	0.487	0.497	12.37	12.62
F	0.635	0.655	16.13	16.64
G	0.022	0.029	0.56	0.74
Н	0.075	0.095	1.91	2.41
J	0.575	0.625	14.61	15.88
K	0.211	0.219	5.36	5.56
L	0.422	0.437	10.72	11.10
М	0.058	0.068	1.47	1.73
N	0.045	0.055	1.14	1.40
Р	0.095	0.115	2.41	2.92
Q	0.008	0.016	0.20	0.41
R	0.008	0.016	0.20	0.41
U	0.164	0.165	4.10	4.20
W	0.085	0.095	2.17	2.42



# **Teccor® brand Thyristors** 35 Amp Standard SCRs

#### **Product Selector**

Part Number	Voltage				Gate Sensitivity	Timo	Package
	400V	600V	800V	1000V	Gate Sensitivity	Туре	гаскаде
Sxx35K	X	X	X	X	40mA	Standard SCR	TO-218AC
Sxx35J	X	X	X		40mA	Standard SCR	TO-218X

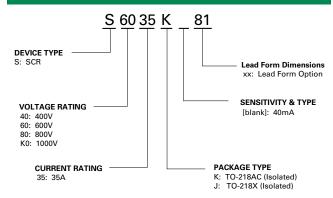
Note: xx = Voltage

### **Packing Options**

Part Number	Marking	Weight	Packing Mode	Base Quantity
Sxx35KTP	Sxx35K	4.40g	Tube	250 (25 per tube)
Sxx35JTP	Sxx35J	5.23g	Tube	250 (25 per tube)

Note: xx = Voltage

# **Part Numbering System**



### **Part Marking System**

TO-218 AC - (K Package) TO-218 X - (J Package)

